## Jungkil Kim

## List of Publications by Year in descending order

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394421 395702 1,411 34 19 33 citations h-index g-index papers 34 34 34 2511 docs citations times ranked citing authors all docs

| #  | Article   | IF   | Citations |
|----|---|------|-----------|
| 1  | Formation of Triboelectric Series <i>via</i> Atomic-Level Surface Functionalization for Triboelectric Energy Harvesting. ACS Nano, 2017, 11, 6131-6138.                                     | 14.6 | 172       |
| 2  | Au/Ag Bilayered Metal Mesh as a Si Etching Catalyst for Controlled Fabrication of Si Nanowires. ACS Nano, 2011, 5, 3222-3229.   | 14.6 | 163       |
| 3  | Plasmon-Enhanced Ultraviolet Photoluminescence from Hybrid Structures of Graphene/ZnO Films.<br>Physical Review Letters, 2010, 105, 127403.   | 7.8  | 127       |
| 4  | Curved Silicon Nanowires with Ribbon-like Cross Sections by Metal-Assisted Chemical Etching. ACS Nano, 2011, 5, 5242-5248.  | 14.6 | 107       |
| 5  | Photon-triggered nanowire transistors. Nature Nanotechnology, 2017, 12, 963-968.  | 31.5 | 95        |
| 6  | Substrate-directed synthesis of MoS2 nanocrystals with tunable dimensionality and optical properties. Nature Nanotechnology, 2020, 15, 29-34.   | 31.5 | 94        |
| 7  | Near-Ultraviolet-Sensitive Graphene/Porous Silicon Photodetectors. ACS Applied Materials & Samp; Interfaces, 2014, 6, 20880-20886.  | 8.0  | 84        |
| 8  | Optical stimulation of cardiac cells with a polymer-supported silicon nanowire matrix. Proceedings of the National Academy of Sciences of the United States of America, 2019, 116, 413-421. | 7.1  | 76        |
| 9  | Graphene/Siâ€Quantumâ€Dot Heterojunction Diodes Showing High Photosensitivity Compatible with Quantum Confinement Effect. Advanced Materials, 2015, 27, 2614-2620.                          | 21.0 | 56        |
| 10 | Graphene/Si-nanowire heterostructure molecular sensors. Scientific Reports, 2014, 4, 5384.  | 3.3  | 47        |
| 11 | Recent Progress in Nanolaser Technology. Advanced Materials, 2020, 32, e2001996.  | 21.0 | 38        |
| 12 | Structural and electronic switching of a single crystal 2D metal-organic framework prepared by chemical vapor deposition. Nature Communications, 2020, 11, 5524.                            | 12.8 | 37        |
| 13 | Airâ∈Bridged Ohmic Contact on Vertically Aligned Si Nanowire Arrays: Application to Molecule Sensors.<br>Advanced Materials, 2012, 24, 2284-2288.   | 21.0 | 35        |
| 14 | Energy transfer from an individual silica nanoparticle to graphene quantum dots and resulting enhancement of photodetector responsivity. Scientific Reports, 2016, 6, 27145.                | 3.3  | 32        |
| 15 | Graphene-Assisted Chemical Etching of Silicon Using Anodic Aluminum Oxides as Patterning Templates.<br>ACS Applied Materials & Diterfaces, 2015, 7, 24242-24246.                            | 8.0  | 30        |
| 16 | Electrically driven strain-induced deterministic single-photon emitters in a van der Waals heterostructure. Science Advances, 2021, 7, eabj3176.  | 10.3 | 28        |
| 17 | A continuous process for Si nanowires with prescribed lengths. Journal of Materials Chemistry, 2011, 21, 15889.   | 6.7  | 27        |
| 18 | Graphene-quantum-dot nonvolatile charge-trap flash memories. Nanotechnology, 2014, 25, 255203.  | 2.6  | 26        |

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|----|--|-----|-----------|
| 19 | Precise and selective sensing of DNA-DNA hybridization by graphene/Si-nanowires diode-type biosensors. Scientific Reports, 2016, 6, 31984.   | 3.3 | 19        |
| 20 | High efficiency n-ZnO/p-Si core–shell nanowire photodiode based on well-ordered Si nanowire array with smooth surface. Materials Science in Semiconductor Processing, 2014, 27, 297-302.                       | 4.0 | 17        |
| 21 | Enhancement of Light Absorption in Silicon Nanowire Photovoltaic Devices with Dielectric and Metallic Grating Structures. Nano Letters, 2017, 17, 7731-7736.   | 9.1 | 17        |
| 22 | Structural and optical characteristics of graphene quantum dots size-controlled and well-aligned on a large scale by polystyrene-nanosphere lithography. Journal Physics D: Applied Physics, 2016, 49, 025308. | 2.8 | 12        |
| 23 | Photon-Triggered Current Generation in Chemically-Synthesized Silicon Nanowires. Nano Letters, 2019, 19, 1269-1274.  | 9.1 | 11        |
| 24 | Selective Pump Focusing on Individual Laser Modes in Microcavities. ACS Photonics, 2018, 5, 2791-2798.   | 6.6 | 10        |
| 25 | Self-assembled growth and luminescence of crystalline Si/SiOxcore–shell nanowires.<br>Nanotechnology, 2010, 21, 205601.  | 2.6 | 9         |
| 26 | Formation of threeâ€dimensional GaAs microstructures by combination of wet and metalâ€assisted chemical etching. Physica Status Solidi - Rapid Research Letters, 2014, 8, 345-348.                             | 2.4 | 9         |
| 27 | Effect of nitrogen doping on the structural and the optical variations of graphene quantum dots by using hydrazine treatment. Journal of the Korean Physical Society, 2015, 67, 746-751.                       | 0.7 | 9         |
| 28 | Recent advances in nanocavities and their applications. Chemical Communications, 2021, 57, 4875-4885.  | 4.1 | 8         |
| 29 | Formation of a Top Electrode on Vertical Si Nanowire Devices Using Graphene as a Supporting Layer.<br>Applied Physics Express, 2012, 5, 105103.  | 2.4 | 5         |
| 30 | Unique Scattering Properties of Silicon Nanowires Embedded with Porous Segments. ACS Applied Materials & Samp; Interfaces, 2019, 11, 21094-21099.  | 8.0 | 4         |
| 31 | Sequential structural and optical evolution of MoS2 by chemical synthesis and exfoliation. Journal of the Korean Physical Society, 2015, 66, 1852-1855.  | 0.7 | 3         |
| 32 | AhnetÂal.Reply:. Physical Review Letters, 2011, 107, .   | 7.8 | 2         |
| 33 | Near-Infrared Photoresponse in Photon-Triggered Nanowire Transistors. Journal of the Korean Physical Society, 2019, 75, 68-72.   | 0.7 | 1         |
| 34 | Si nanowires with porous segments for photon-triggered transistors. Journal Physics D: Applied Physics, 2019, 52, 373001.  | 2.8 | 1         |